# 2N1613

## SILICON NPN TRANSISTOR

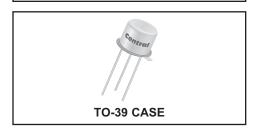


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# **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR 2N1613 is a silicon NPN epitaxial planar transistor designed for small signal general purpose switching applications.

MARKING: FULL PART NUMBER



MAXIMUM RATINGS: (T<sub>A</sub>=25°C unless otherwise noted)

	SYMBOL		UNITS	
Collector-Base Voltage	$V_{CBO}$	75	V	
Collector-Emitter Voltage	VCER	50	V	
Emitter-Base Voltage	$V_{EBO}$	7.0	V	
Continuous Collector Current	I <sub>C</sub>	500	mA	
Power Dissipation (T <sub>C</sub> =25°C)	$P_{D}$	3.0	W	
Power Dissipation	$P_{D}$	0.8	W	
Operating and Storage Junction Temperature	$T_{\rm II}, T_{\rm sta}$	-65 to +200	°C	

**ELECTRICAL CHARACTERISTICS:** (T<sub>A</sub>=25°C unless otherwise noted)

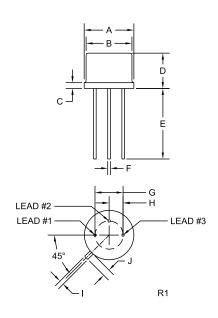
TEST CONDITIONS	MIN	MAX	UNITS
V <sub>CB</sub> =60V		10	nA
V <sub>EB</sub> =5.0V		10	nA
I <sub>C</sub> =100μA	75		V
$I_C$ =10mA, $R_{BE}$ =10 $\Omega$	50		V
I <sub>E</sub> =100μA	7.0		V
I <sub>C</sub> =150mA, I <sub>B</sub> =15mA		1.5	V
I <sub>C</sub> =150mA, I <sub>B</sub> =15mA		1.3	V
$V_{CE} = 10V, I_{C} = 100 \mu A$	20		
V <sub>CE</sub> =10V, I <sub>C</sub> =10mA	35		
V <sub>CE</sub> =10V, I <sub>C</sub> =150mA	40	120	
$V_{CE}$ =10V, $I_{C}$ =500mA	20		
$V_{CE}$ =10V, $I_{C}$ =50mA, f=20MHz	60		MHz
$V_{CB}$ =10V, $I_E$ =0, f=100kHz		25	pF
$V_{EB}$ =0.5V, $I_{C}$ =0, f=100kHz		80	pF
$V_{CE}$ =10V, $I_{C}$ =300 $\mu$ A, f=1.0 $k$ Hz		12	dB
	TEST CONDITIONS $V_{CB}=60V$ $V_{EB}=5.0V$ $I_{C}=100\mu A$ $I_{C}=100\mu A$ $I_{C}=150mA$ , $I_{B}=15mA$ $I_{C}=150mA$ , $I_{B}=15mA$ $I_{C}=150mA$ , $I_{C}=100\mu A$ $I_{C}=10V$ , $I_{C}=100\mu A$ $I_{C}=10V$ , $I_{C}=100mA$	$\begin{array}{llllllllllllllllllllllllllllllllllll$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$

# 2N1613

# SILICON **NPN TRANSISTOR**



## **TO-39 CASE - MECHANICAL OUTLINE**



DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
A (DIA)	0.335	0.370	8.51	9.40		
B (DIA)	0.315	0.335	8.00	8.51		
С	-	0.040	-	1.02		
D	0.240	0.260	6.10	6.60		
Е	0.500	-	12.70	-		
F (DIA)	0.016	0.021	0.41	0.53		
G (DIA)	0.200		5.08			
Н	0.100		2.54			
	0.028	0.034	0.71	0.86		
J	0.029	0.045	0.74	1.14		

TO-39 (REV: R1)

## LEAD CODE:

- 1) Emitter 2) Base
- 3) Collector

MARKING: FULL PART NUMBER

## **OUTSTANDING SUPPORT AND SUPERIOR SERVICES**



#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

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- · Custom bar coding for shipments
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- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- · PbSn plating options
- Package details
- · Application notes
- · Application and design sample kits
- · Custom product and package development

#### **CONTACT US**

#### Corporate Headquarters & Customer Support Team

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